Supplementary Information

High Sensitivity and Fast Response Self-Powered Solar-Blind Ultraviolet Photodetector with β-Ga2O3/Spiro-MeOTAD p-n Heterojunction

Zuyong yan^{a,b}, shan li^{a,b}, Zeng Liu^{a,b}, yusong zhi^{a,b}, Jie Dai^{a,b}, xiangyu sun^b, Siyuan Sun^{a,b}, daoyou guo^{a,b}, xia wang^{a,b}, peigang li^{*,a,b}, zhenping wu^{a,b}, Lily Li^c, weihua tang^{*,a,b}

^a Laboratory of information functional materials and devices, school of science, Beijing university of posts and telecommunications, Beijing 100876, china.

^b State key laboratory of information photonics and optical communications, Beijing university of posts and telecommunications, Beijing 100876, china.

^c Department of Physics, The State University of New York at Potsdam, Potsdam, NY 13676, USA.

*E-mail: pgli@bupt.edu.cn.

*E-mail: whtang@bupt.edu.cn.



Figure S1. the spectral responsivity in logarithmic scale



Figure S2. Comparison of time-dependent response of the Ga2O3/Spiro-MeOTAD p-n junction device before and after one month under zero bias



Figure S3. The shapes of photocurrent curves with a rounded head under UV light with the power intensity of 1 μ W/cm² and a wedgy head under 80 μ W/cm².